



Radiation analysis and test of CMOS sensors for TEM applications Work Package 5

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Smart Sensor Technologies and Training for Radiation Enhanced Applications and Measurements (STREAM) is a project funded by the European Commission under the Horizon2020 Framework Program under the Grant Agreement no 675587. STREAM began in January 2016 and will run for 4 years.



ESR13: Aims of the project

- Transmission electron microscope integration and test of HPIXEL, the KIT designed HV-CMOS particle detector
- Characterisation and assessment of HPIXEL for electron microscopy
- Radiation hardness analysis of the MALTA detector
- Identification possible fields of application or guidance for future re-design





Malta radiation test

- MALTA TID(total ionizing dose) hardness tested at CERN with X-ray machine
- Measurements taken at different dose levels: 0, 5, 20 and 70 MRad

Several measurements at each stage:

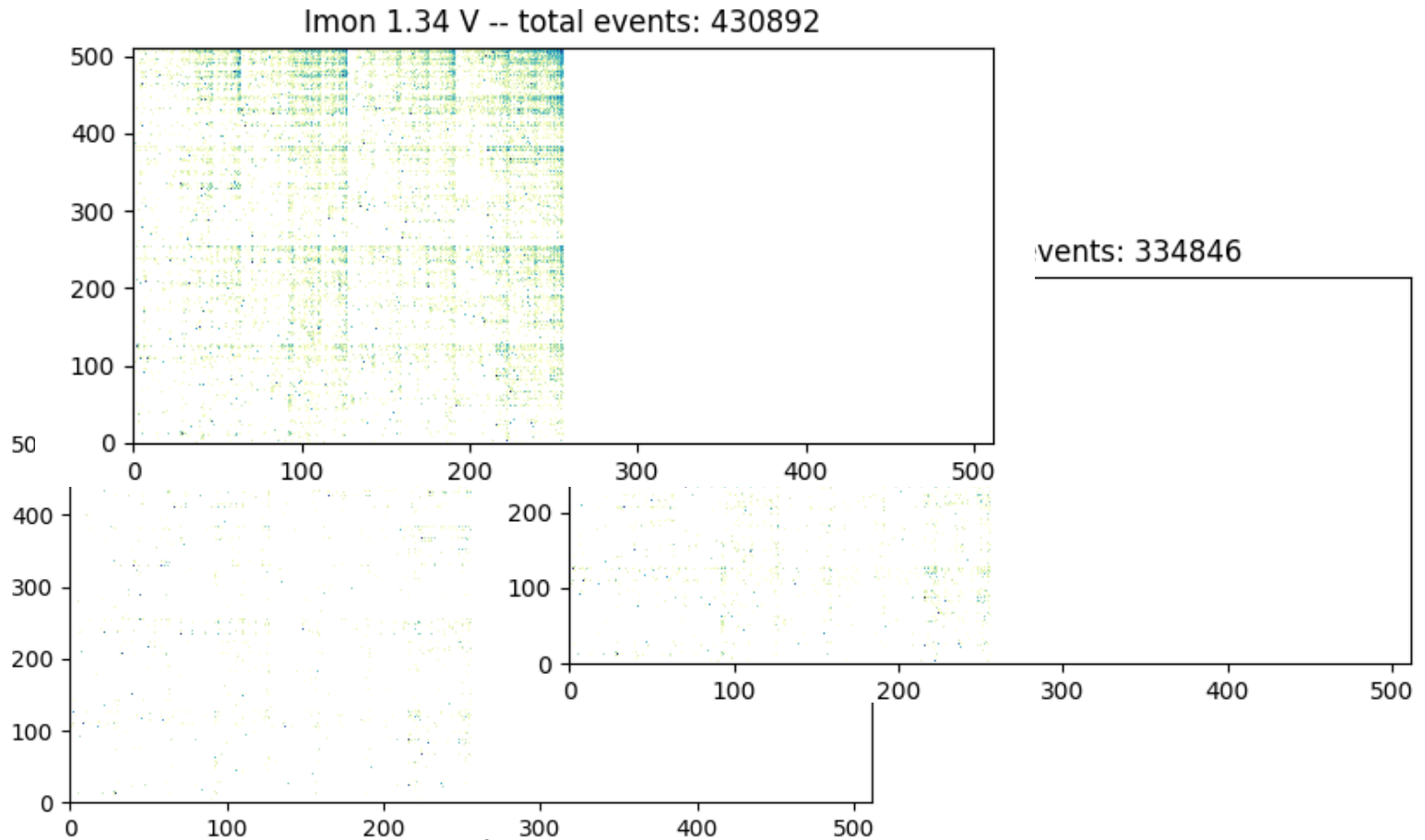
1. Noise level by number of events + threshold dependency
2. Power supply analysis
3. Pixel-to-pixel threshold variation
4. Gain analysis



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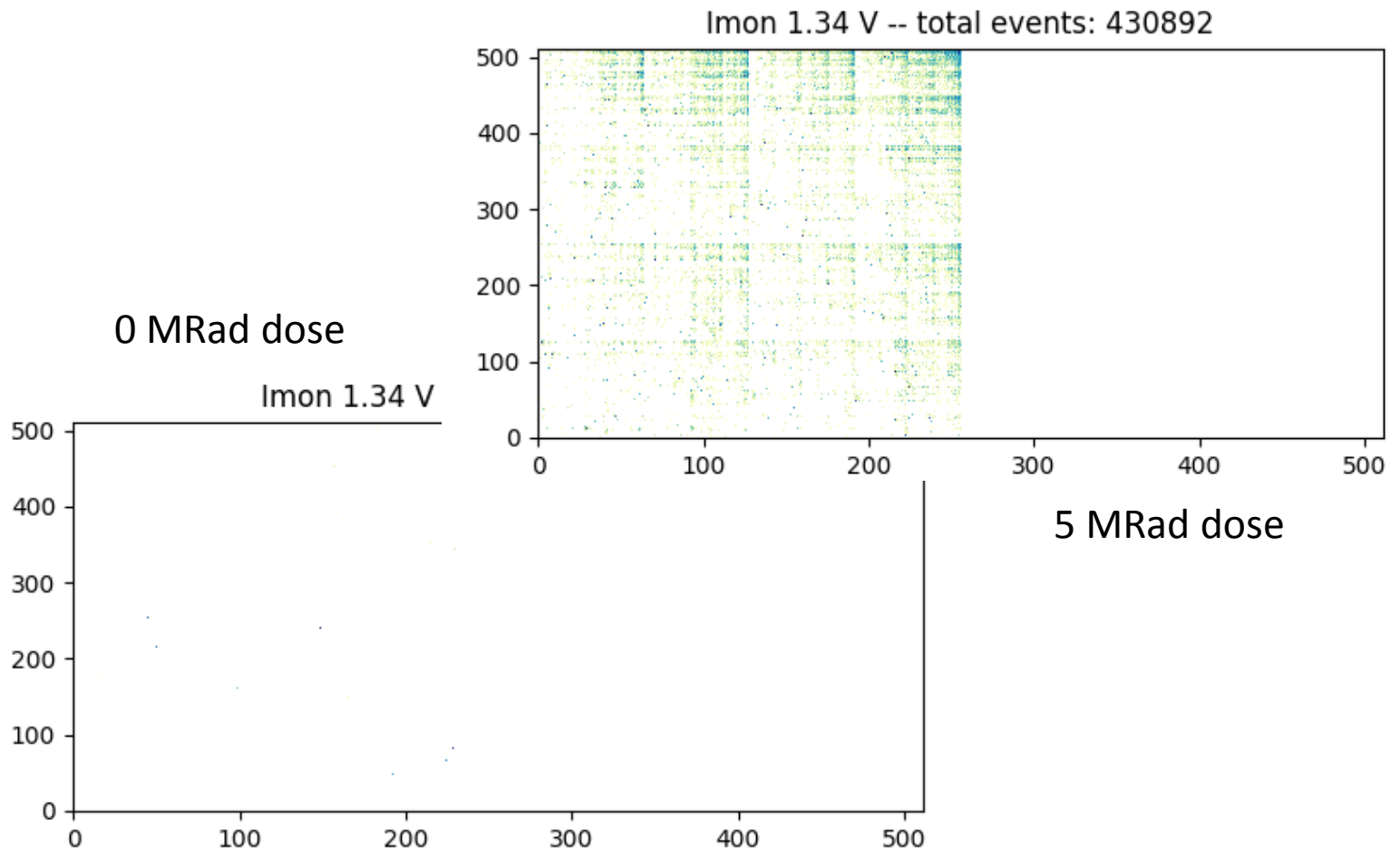
Malta radiation test

Total noisy events: 5 Mrad level



Malta radiation test

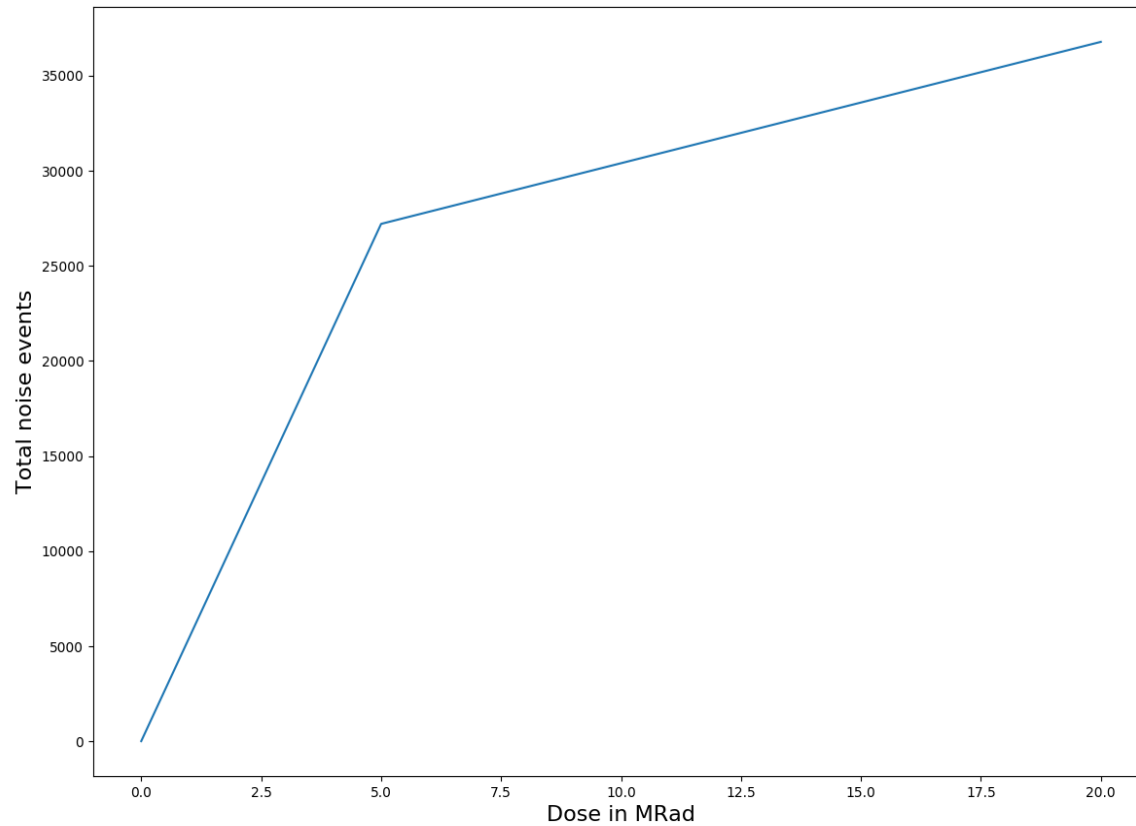
Total noisy events: Example: 0 to 5 MRad



Malta radiation test

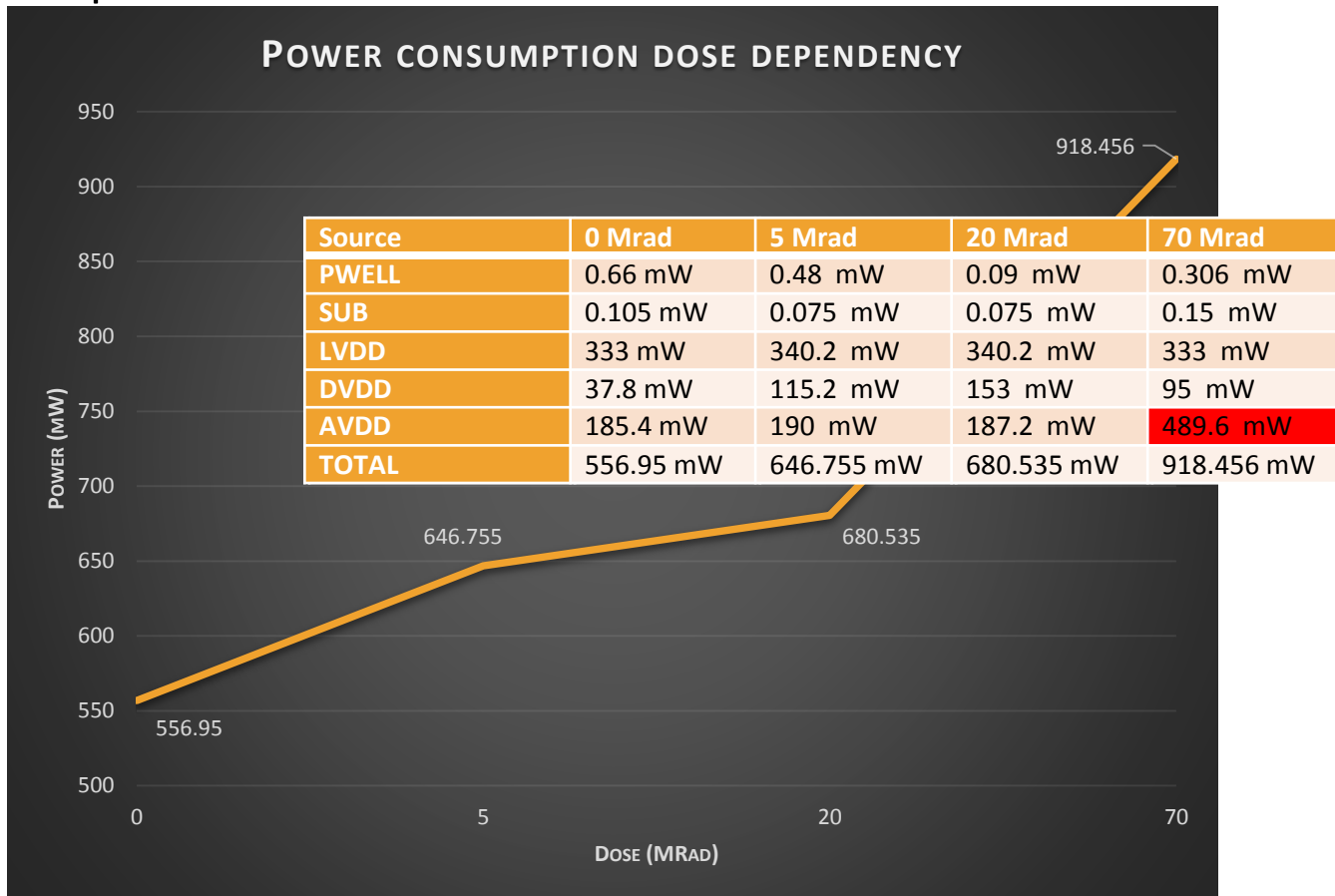
Total noisy events: 0, 5, 20 MRad points (sensor breakdown at 70 MRad)

Radiation effects at 1.26 IMON and 100x50 integration time - 0 to 20 MRad noise events



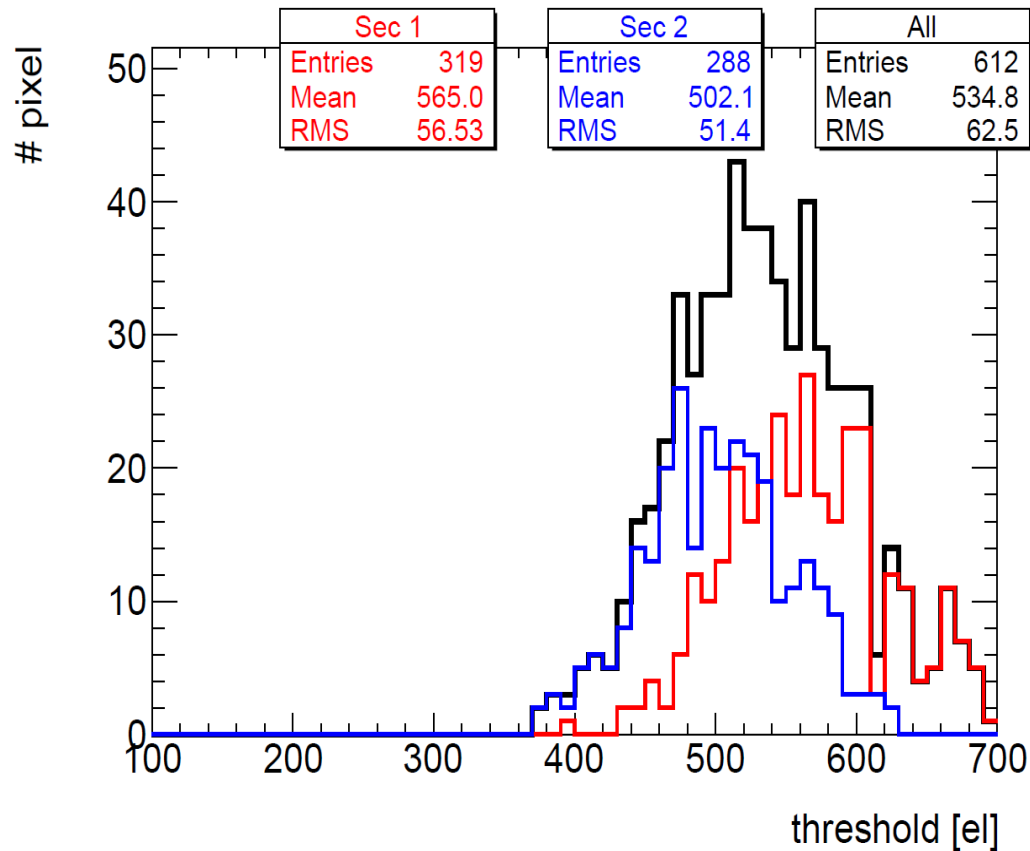
Malta radiation test

Power dissipation - 70Mrad value mainly due to AVDD going to compliance.



Malta radiation test

Threshold dispersion - weak increase in standard deviation: from 48 RMS unirradiated to 62.5 at 70 MRad

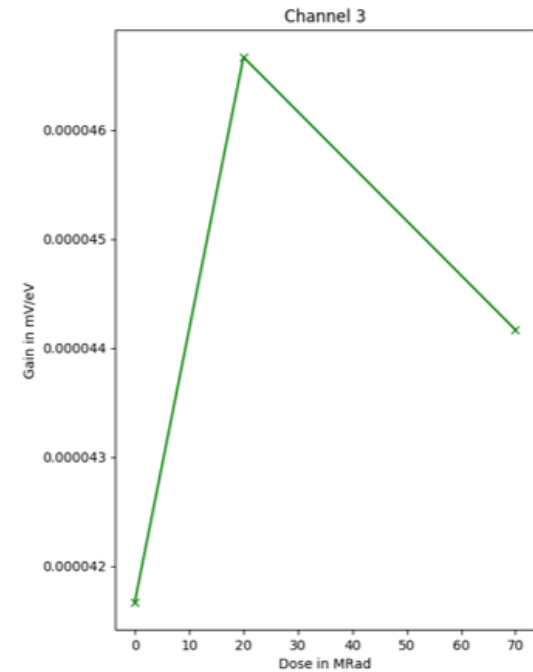
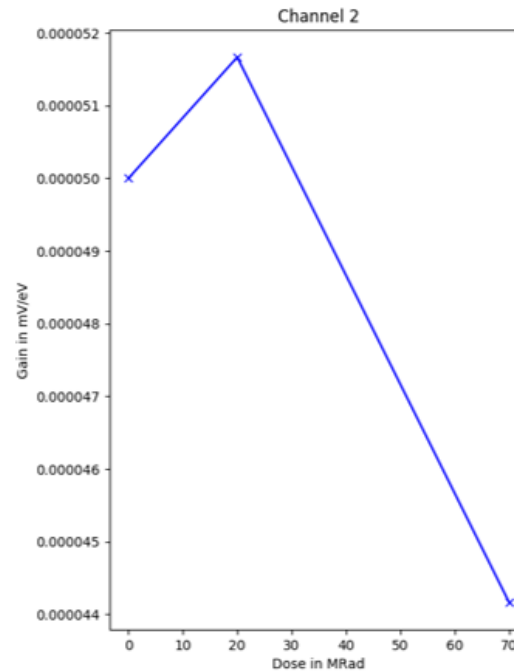
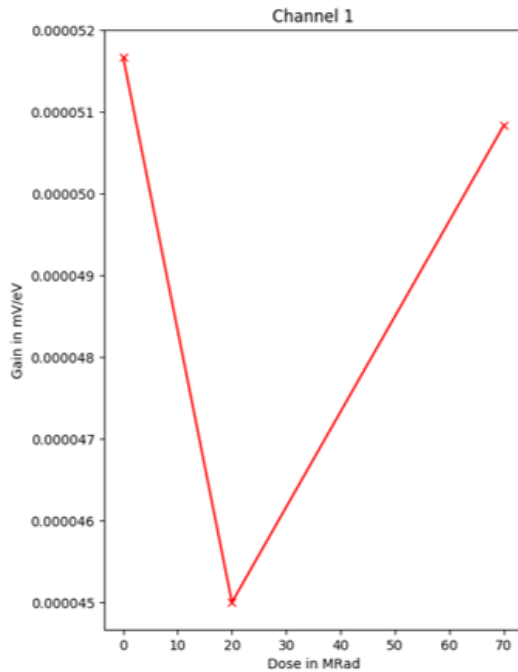


Malta radiation test

Gain variation – test with Fe55 source

- No substantial variation

Analog pixels gain behaviour with ionising dose

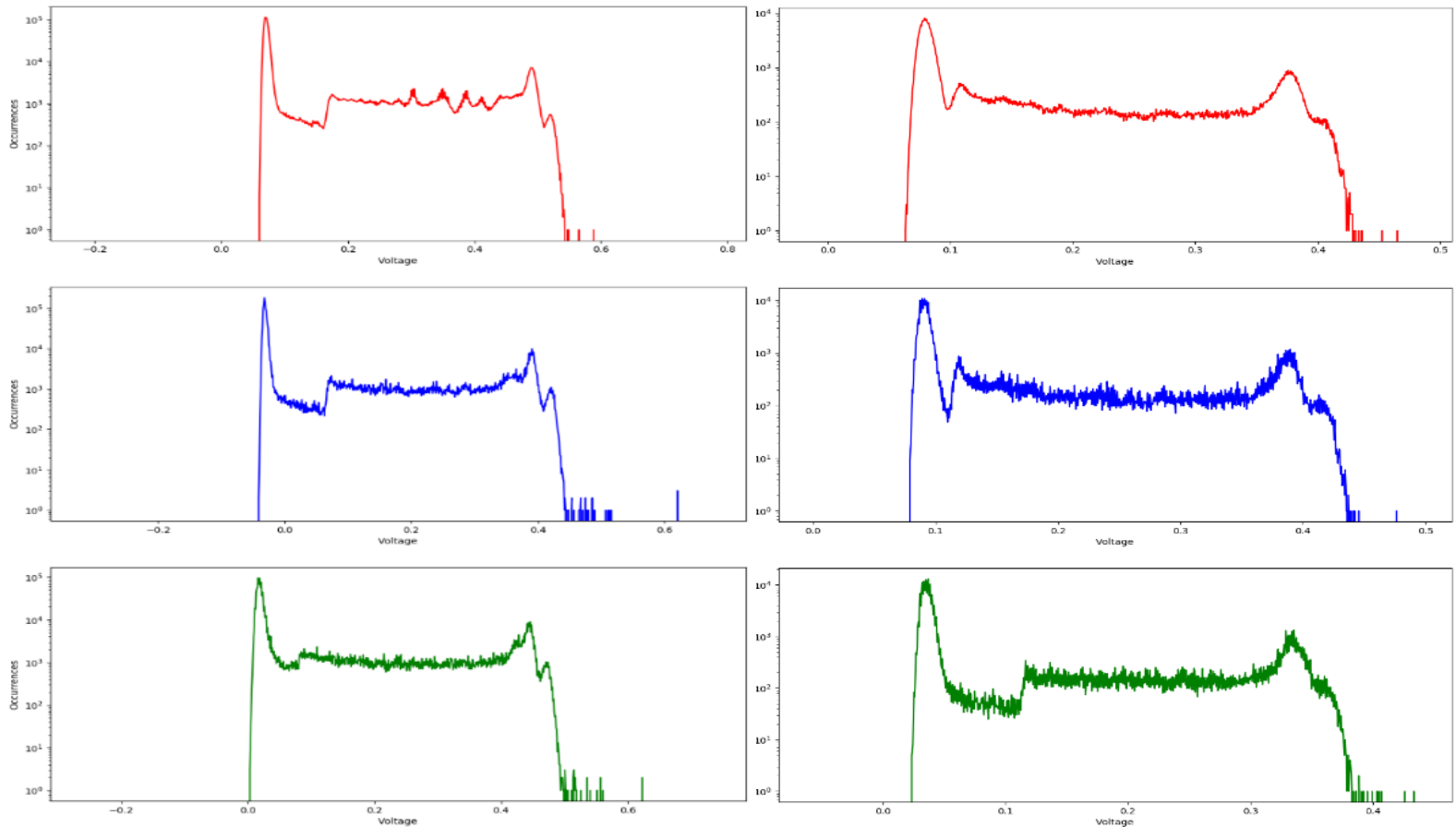


Malta radiation test

Gain variation – Peaks width doubled: chip is noisier – more events!

Unirradiated

70 MRad





Malta radiation test

Summary

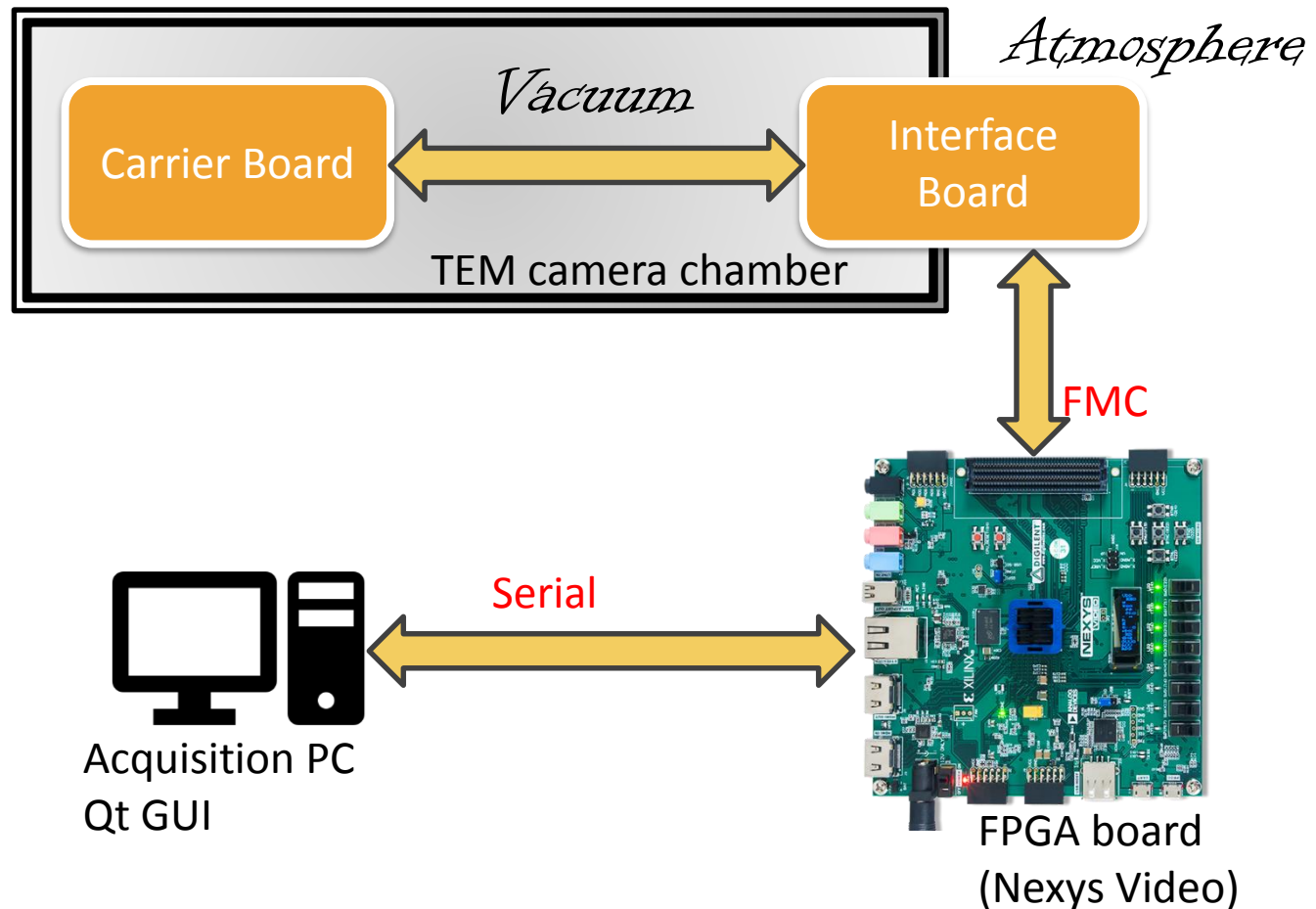
- Actual chip non-usable for low-threshold applications with doses of 70 MRad and higher due to strong noise activity and power dissipation
- Digital electronics and LVDS drivers seem to withstand ionizing dose, so does analogue front-end as gain does not seem to change with radiation



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Hpixel progress – System setup

Measurement system setup with Nexys Video board

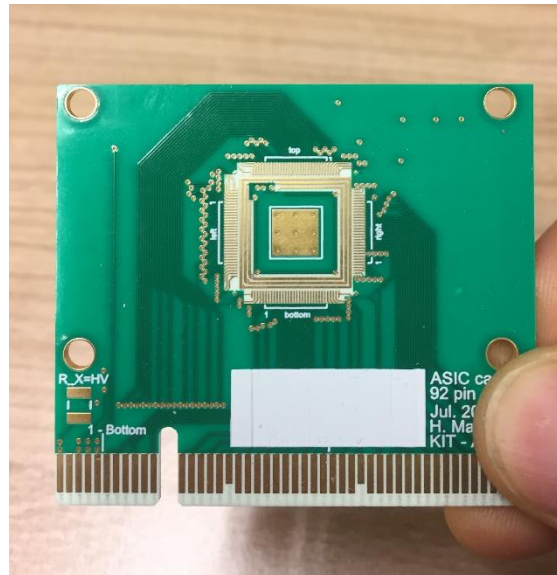


HPixel integration

Power plugs were on carrier board: inaccessible

New compact PCBs designed

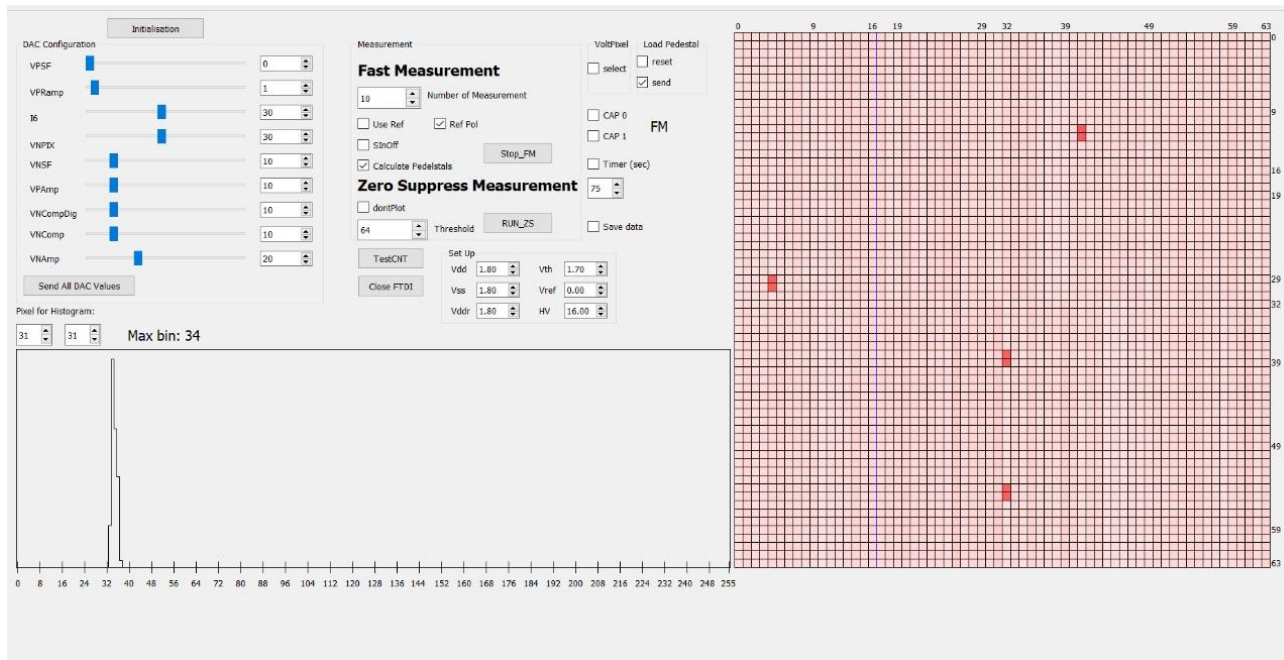
- Interface PCB broader, with power plugs and trim control connector
- 90 degree connector to sensor board: saves internal space
- Smaller carrier PCB: few components and sensor directly bonded on the board



HPixel integration

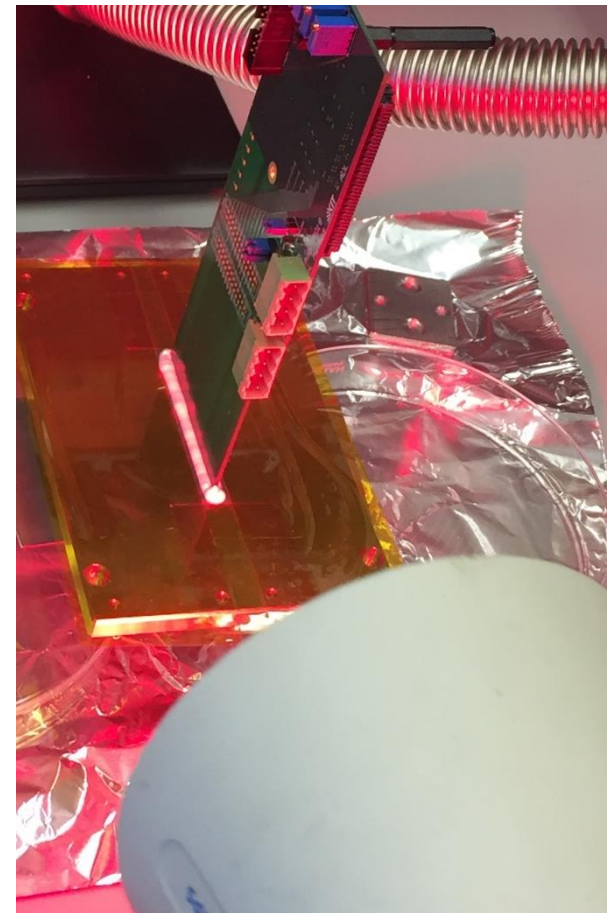
Example of desk test to verify functionality - repeated at different stages

Noise floor standing around 34 DN best-case (digital numbers)



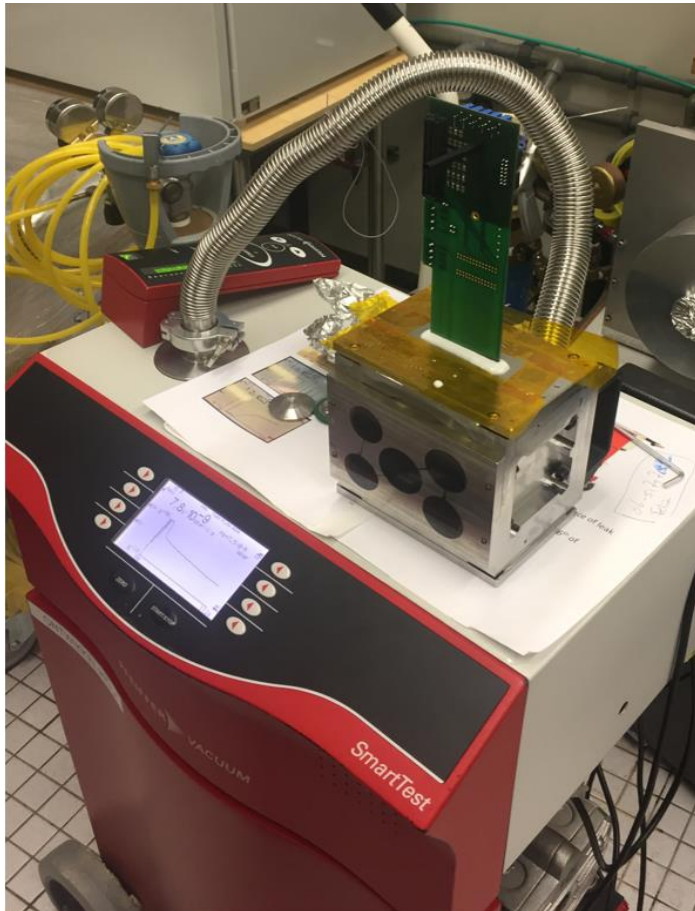
HPixel integration

Vacuum compatibility: epoxy resin application on the flange slot



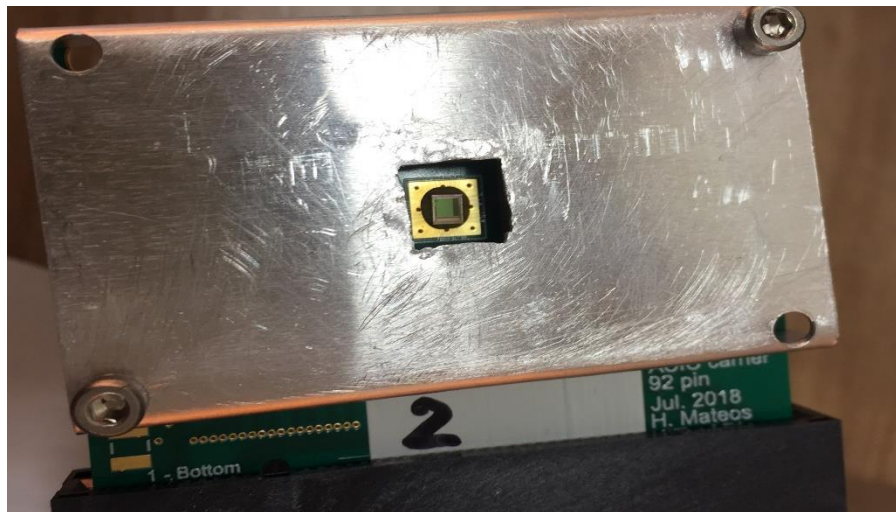
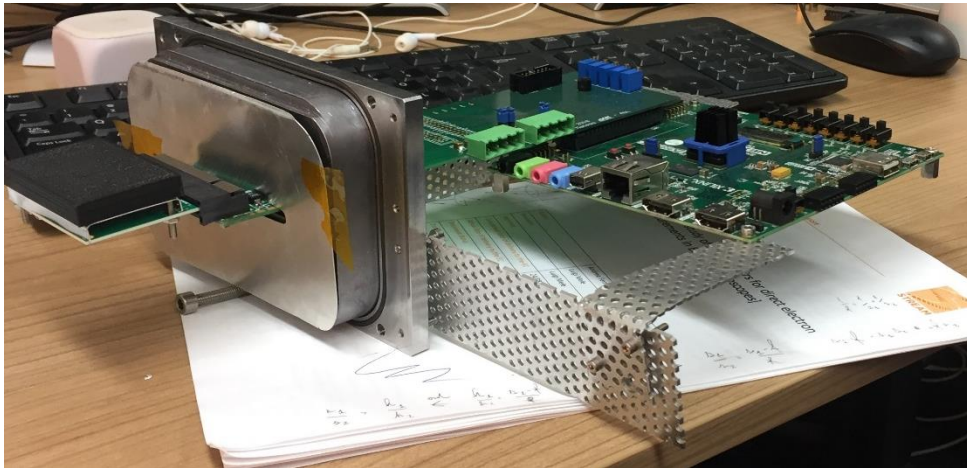
HPixel integration

Vacuum compatibility: test with vacuum pump



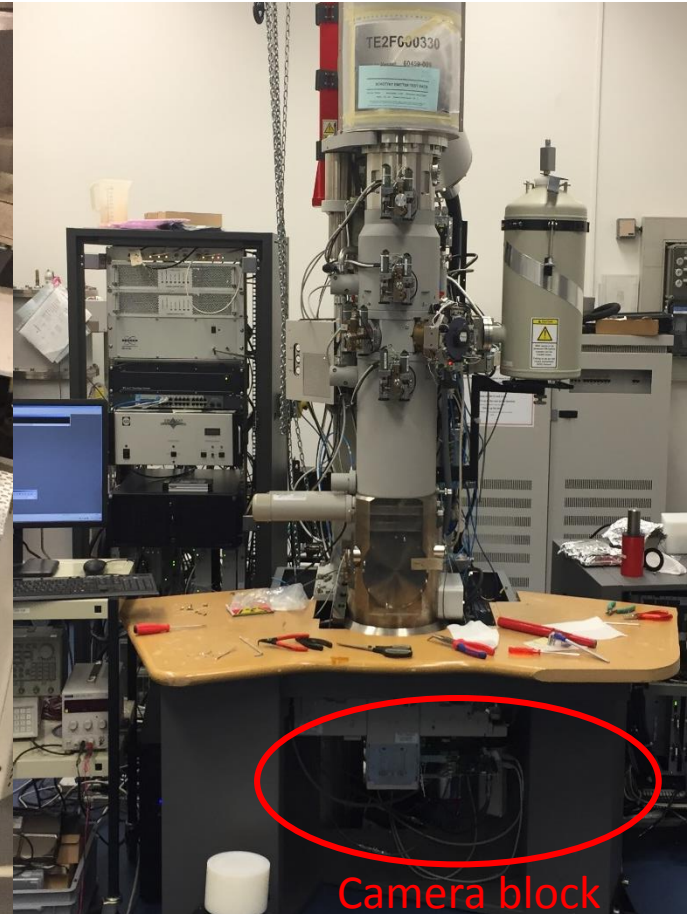
HPixel integration

Mechanical support and shielding for the system



HPixel integration

TEM integration





HPixel test

First tests on the TEM in mid December 2018

- HPIXEL detector exposed to a 200keV electron beam
- Broke down with a beam current of $\sim 9\text{nA}$ (probably latch-up event in readout electronics) -> further investigation on radiation hardness needed



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HPixel test

January 2019 tests at the Thermo Fisher Scientific facility:

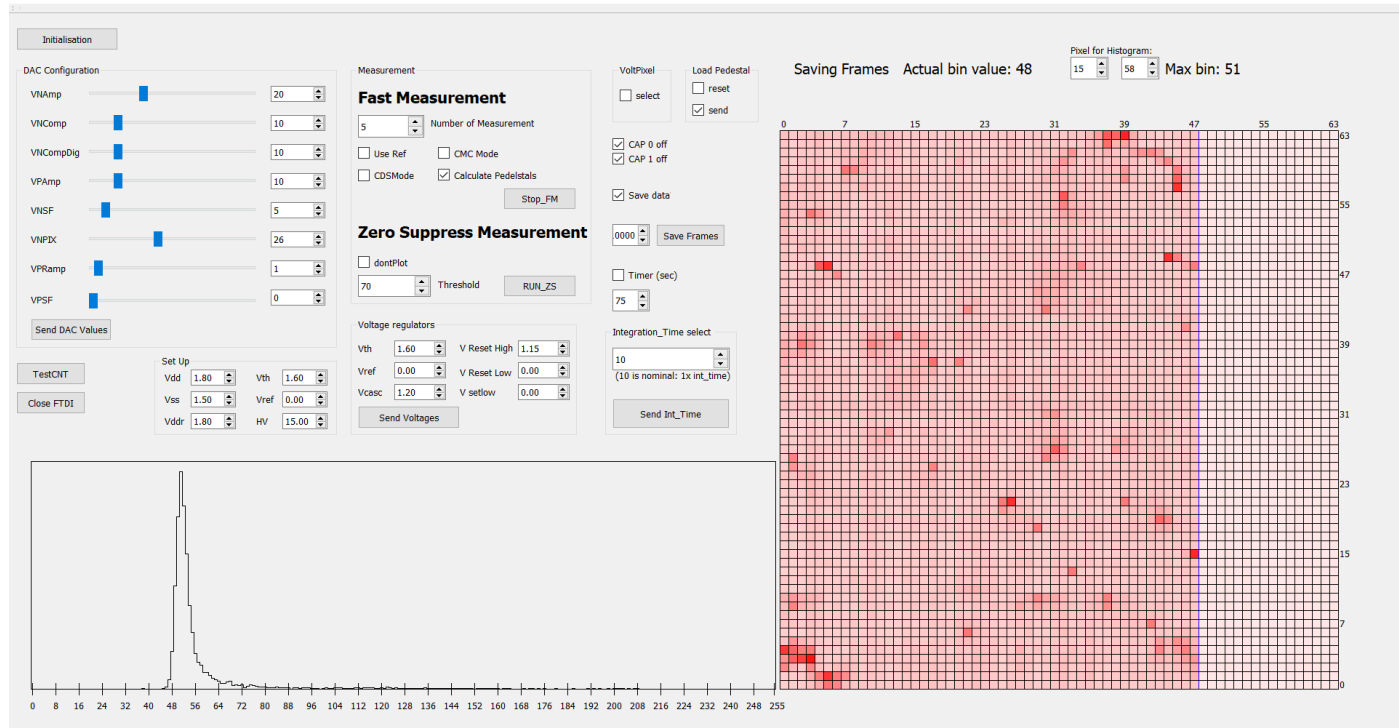
- Supported by ESR4 from KIT
- Measurements at very low currents, single electron events
- Characterization of the detector at different High Voltage levels: gain, blob size.



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HPixel test

Chip tested at very low doses in TEM

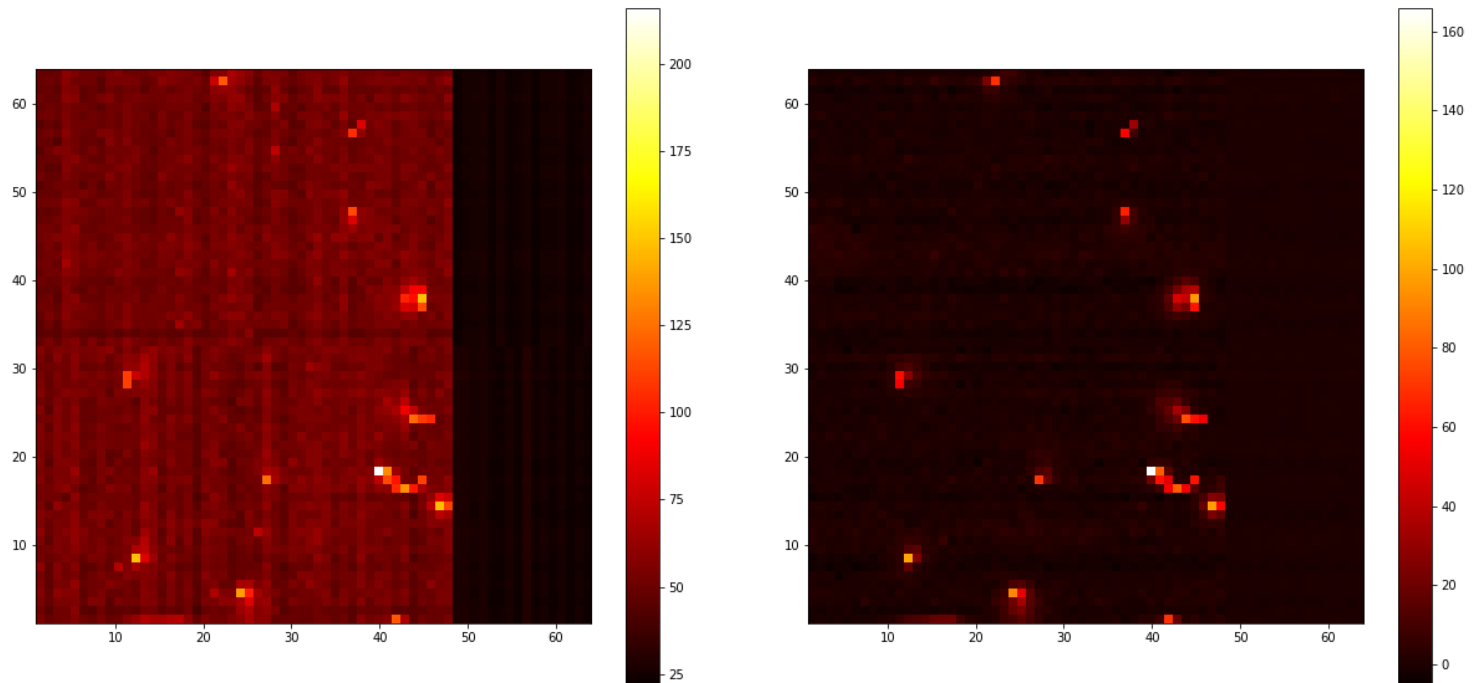


HPixel test

Blob size with HV - most of the processing to be done

At -40HV biasing, deviation of charge events around 0.18.

Laplacian of Gaussian approach to detect blobs and deviation

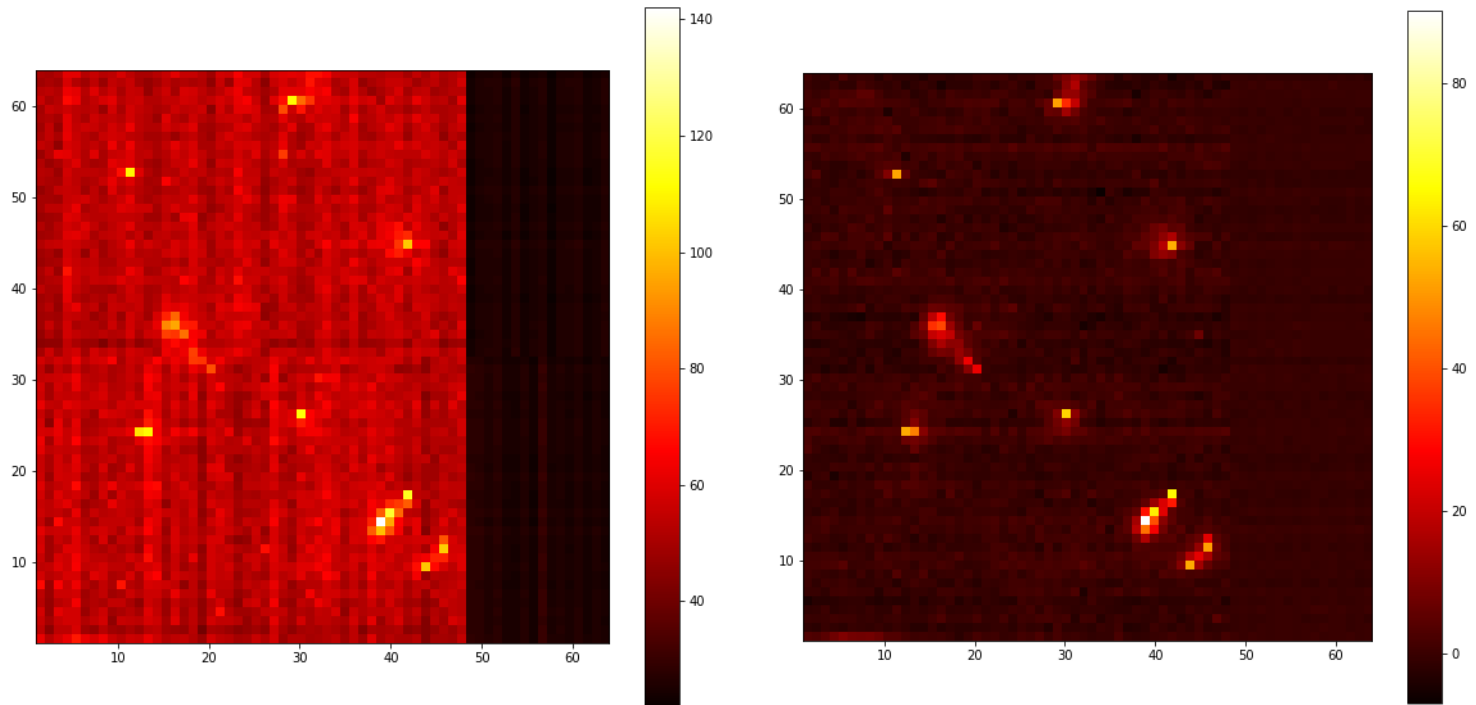


HPixel test

Blob size with HV - most of the processing to be done

At 0HV biasing, deviation of charge events around 0.177.

Why lower? -> might be low statistics or radiation effects





HPixel test

- Processing for gain analysis still to be conducted
- But chip started to break down at low radiation levels
- 2/2 chips broken: -> to investigate why HPIXEL seems not radiation tolerant to ionizing radiation?



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Thanks for the attention!

Q&A